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Class
ISSUE CLASSIFICATION

PATENT NUMBER

U.S. UTILITY Patent Application

JC 3 257

O.I.P.E.

PATENT DATE

SCANNED

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APPLICATION NO.	CONT/PRIOR	CLASS	SUBCLASS	ART UNIT	EXAMINER
09/691456	F	438 257	555	2912 2811	Gebremed

APPLICANTS
Hisamitsu SuzukiTITLE
Shallow trench isolation structure for a bipolar transistorPTO-2040
12/99

ISSUING CLASSIFICATION

ORIGINAL		CROSS REFERENCE(S)			
CLASS	SUBCLASS	CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)		
INTERNATIONAL CLASSIFICATION					
Continued on Issue Slip Inside File Jacket					

TERMINAL DISCLAIMER	DRAWINGS			CLAIMS ALLOWED	
	Sheets	Drawg.	Figs.	Drawg.	Print. Fig.
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<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S. Patent No. _____				NOTICE OF ALLOWANCE MAILED	
<input type="checkbox"/> The terminal _____ months of this patent have been disclaimed.				ISSUE FEE	
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